P.03

## Application No. 10/777,156

## Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

- 1. (Previously Presented) A protection circuit, to be provided for a circuit arrangement having an inductive load and an FET as an N-channel MOS transistor provided upstream of the load with respect to a flow of power current, the FET controlling an energization state of the load, the protection circuit comprising:
- a first connection changer interposed on a connection line between a gate of the FET and a gate drive voltage supply source, the first connection changer changing a connection state between a first connection state in which the gate is connected to the gate drive voltage supply and a second connection state in which the gate is connected to a ground; and
  - a first resistor interposed between the gate and a source of the FET,
- wherein the protection circuit does not include a zener diode, and protects from overvoltage generated by the load upon discontinuing power to the load.
- 2. (Previously Presented) The protection circuit according to claim 1, further comprising:
- a second resistor interposed between the gate and the first connection changer or between the first connection changer and the ground.
  - 3. (Original) The protection circuit according to claim 2, further comprising:
- a second connection changer interposed on a connection line between the gate and the source of the FET, the second connection changer for connecting and disconnecting the connection line;
  - wherein the first resistor is interposed on the connection line.
- 4. (Currently Amended) A protection circuit, to be provided for a circuit arrangement having an inductive load and an FET as an N-channel MOS transistor provided upstream of

the load with respect to a flow of power current, the FET controlling an energization state of the load, the protection circuit comprising:

a first connection changer interposed between a portion on a first connection line and a ground, the first connection changer connecting and disconnecting between the portion and the ground; and

a first resistor interposed on a second connection line between the gate and a source of the FET, wherein the first connection line connects a gate of the FET and a gate drive voltage supply source, and

wherein the protection circuit does not include a zener diode, and protects from overvoltage generated by the load upon discontinuing power to the load.

5. (Previously Presented) The protection circuit according to claim 4, further comprising:

a second resistor interposed on a route from the gate to the ground through the first connection line and the connection changer.

6. (Original) The protection circuit according to claim 5, further comprising:

a second connection changer interposed on the second connection line between the gate and the source of the FET, the second connection changer connecting and disconnecting the second connection line;

wherein the first resistor is interposed in the second connection line.

7-8. (Cancelled)

9. (Previously Presented) A protection circuit, to be provided for a circuit arrangement having an inductive load and an IGBT provided upstream of the load with respect to a flow of power current, the IGBT controlling an energization state of the load, the protection circuit comprising:

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a connection changer interposed on a connection line between a gate of the IGBT and a gate drive voltage supply source, the connection changer changing a connection state between a first connection state in which the gate is connected to the gate drive voltage supply and a second connection state in which the gate is connected to a ground; and

wherein the protection circuit does not include a zener diode, and protects from overvoltage generated by the load upon discontinuing power to the load.

a first resistor interposed between the gate and an emitter of the IGBT,

10. (Previously Presented) The protection circuit according to claim 9, further comprising:

a second resistor interposed between the gate of the IGBT and the connection changer or between the connection changer and the ground.

11. (Previously Presented) A protection circuit, to be provided for a circuit arrangement having an inductive load and an IGBT provided upstream of the load with respect to a flow of power current, the IGBT controlling an energization state of the load, the protection circuit comprising:

a connection changer interposed between a portion on a connection line and a ground, the connection changer connecting and disconnecting between the portion and the ground; and

a first resistor interposed between the gate and an emitter of the IGBT;

wherein the connection line connects a gate of the IGBT and a gate drive voltage supply source, and

wherein the protection circuit does not include a zener diode, and protects from overvoltage generated by the load upon discontinuing power to the load.

12. (Previously Presented) The protection circuit according to claim 11, further comprising:

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a second resistor interposed on a route from the gate of the IGBT to the ground through the connection line and the connection changer.